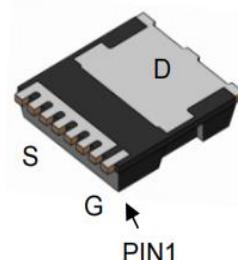




1. Features

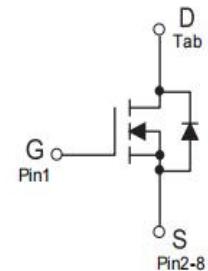
- V_{DS} 150V
- I_D (at $V_{GS}=10V$) 240A
- $R_{DS(ON)}$ (at $V_{GS}=10V$) 3.4m Ω (Typ)

TOLL



2. Mechanical Data

- Case:Molded Plastic,TOLL .
- Epoxy:UL 94V-0 rate flame retardant
- Terminals:Plated Leads Solderable perMIL-STD-750,Method-2026.
- Marking:XNTL1504
- Mounting Position : Any.



3. Maximum Ratings and Electrical Characteristics

Rating at 25°C ambient temperature unless otherwise specified.

Parameter	Symbol	Value	UNIT
Drain-Source Voltage	V_{DS}	150	V
Gate-Source Voltage	V_{GS}	± 20	V
Continuous Drain Current	I_D	240	A
		162	
Drain Current-Continuous(Package Limited)	I_D	781	A
Power Dissipation	P_{tot}	500	W
Avalanche Energy, Single Pulsed ⁽¹⁾	E_{AS}	1796	mJ
Thermal Resistance from Junction to Lead	$R_{\theta JC}$	0.3	°C/W
Thermal Resistance from Junction to Ambient	$R_{\theta JA}$	25	°C/W
Junction and Storage Temperature Range	T_J, T_{STG}	-55~ +175	°C



4. Electrical Characteristics

Rating at 25°C ambient temperature unless otherwise specified.

Parameter	Symbol	Test Condition	Min	Typ	Max	Units
Off Characteristics						
Drain-source breakdown voltage	V _{(BR) DSS}	V _{GS} = 0V, I _D = 250μA	150			V
Zero gate voltage drain current	I _{DSS}	V _{DS} = 150V, V _{GS} = 0V			1	μA
Gate-source leakage current	I _{GSS}	V _{GS} = ±20V, V _{DS} = 0V			±100	nA
On characteristics						
Drain-source on-resistance	R _{DS(on)}	V _{GS} = 10V, I _D = 20A		3.4	4.1	mΩ
Gate threshold voltage	V _{GS(th)}	V _{DS} = V _{GS} , I _D = 250μA	2.5	3.4	4.5	V
Dynamic Characteristics						
Input capacitance	C _{iss}	V _{DS} = 75V, V _{GS} = 0V, f = 1MHz		6235		pF
Output capacitance	C _{oss}			783		pF
Reverse transfer capacitance	C _{rss}			23		pF
Switching Characteristics						
Gate charge total	Q _g	V _{DS} = 75 V, I _D = 20 A, V _{GS} = 10 V		91		nC
Gate-Source Charge	Q _{gs}			26		nC
Gate-Drain Charge	Q _{gd}			21		nC
Turn-on delay time	t _{d(on)}	V _{DD} = 75 V, V _{GS} = 20V, R _L = 3.3Ω		20		nS
Turn-on rise time	t _r			41		nS
Turn-off delay time	t _{d(off)}			58		nS
Turn-off fall time	t _f			44		nS
Source-Drain Diode characteristics						
Body Diode Voltage	V _{SD}	I _{SD} = 40A, V _{GS} = 0V			1.2	V
Reverse Recovery Time	t _{rr}	I _F = 40A dI _F /dt = 500A/μs		103		ns
Reverse Recovery Charge	Q _{rr}			431		nC

Note:

1. Repetitive Rating : Pulsed width limited by maximum junction temperature.
2. V_{DD}=75V, V_{GS}=10V, L=1.0mH, Starting TJ=25°C
3. The data tested by pulsed , pulse width ≤ 300us , duty cycle ≤ 2%.
4. Essentially independent of operating temperature.



5. Rating And Characteristic Curves

Fig1: Output Characteristics

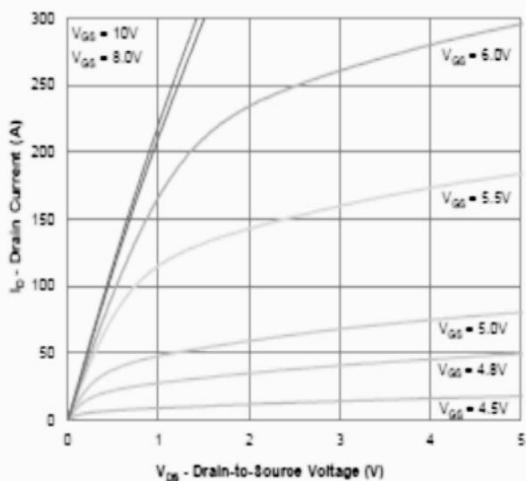


Fig2: Transfer Characteristics

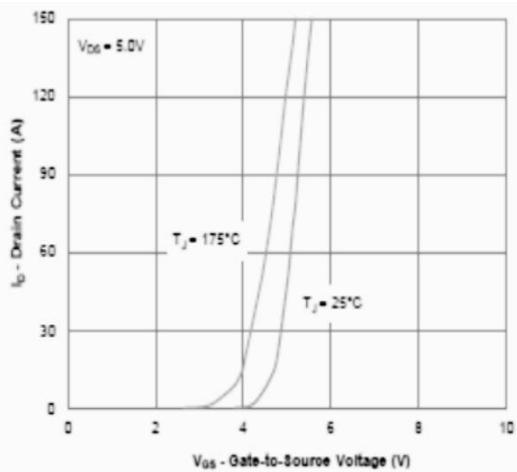


Fig.3 Rdson Vs Ids Characteristics($T_c=25^\circ\text{C}$)

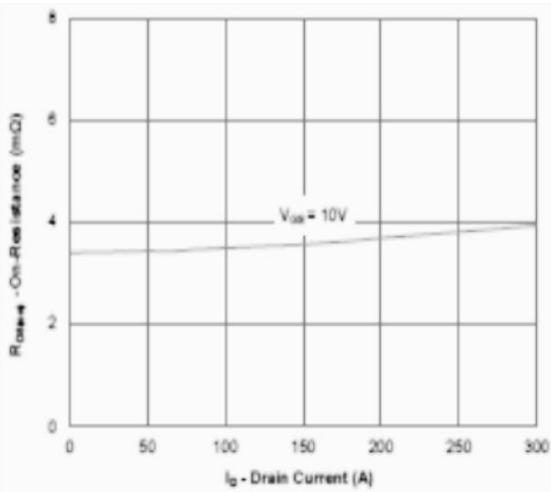


Fig.4 Rds(on) vs Gate Voltage

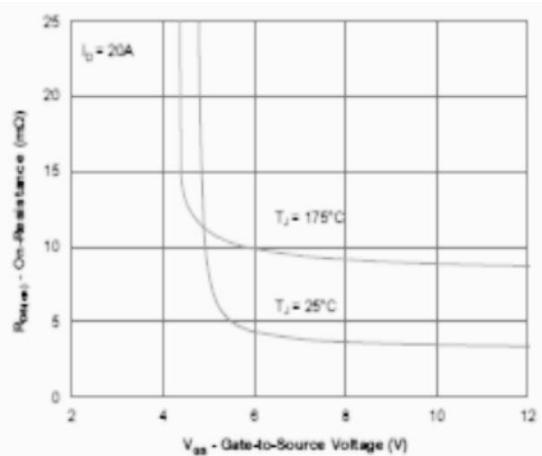


Fig.5 Rds(on) vs. Temperature

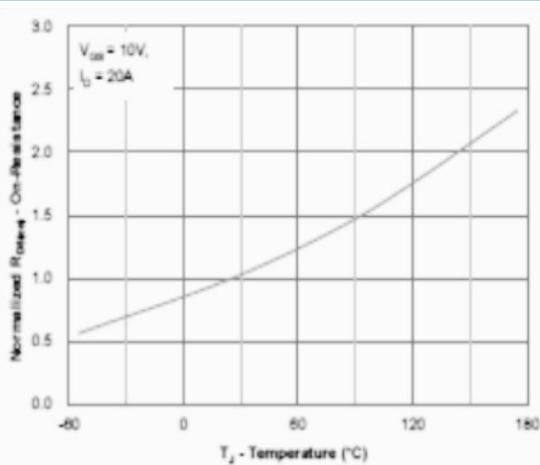


Figure 6: On-Resistance vs. Junction Temperature

Fig.6 Safe Operating Area

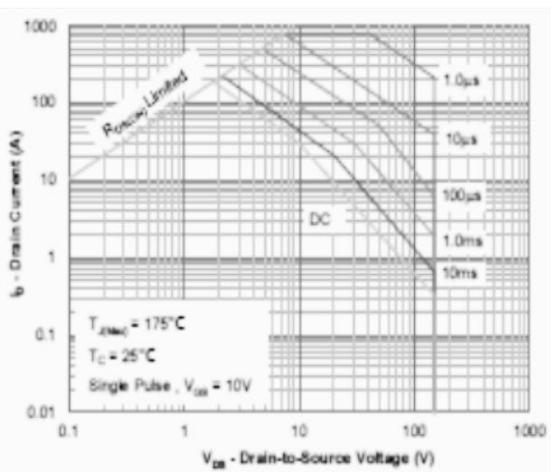


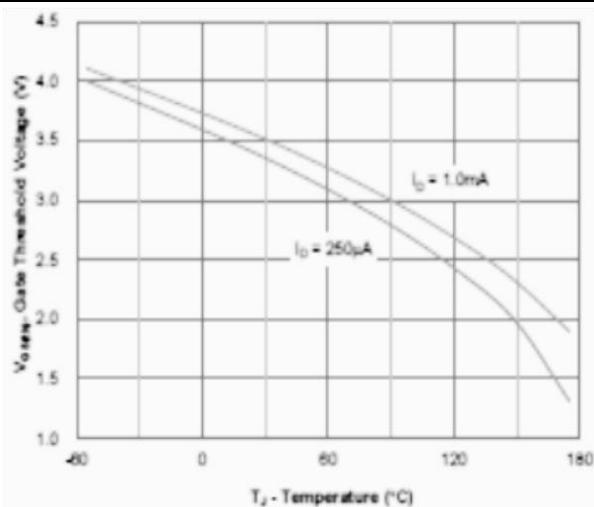
Fig.7 Gate Threshold variation vs. T_J 

Fig.8 Capacitance Characteristics

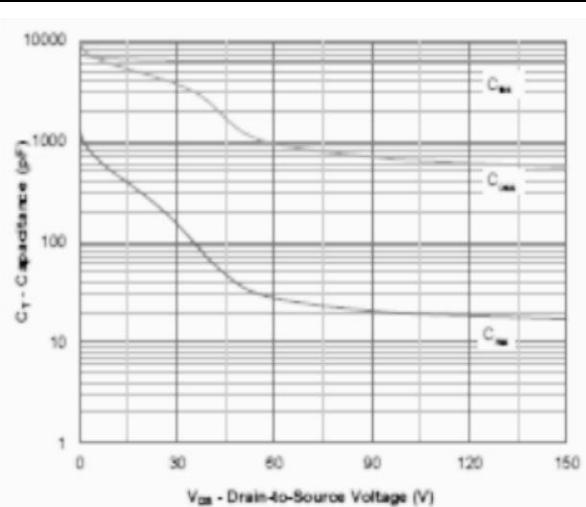


Fig.9 Gate Charge characteristics

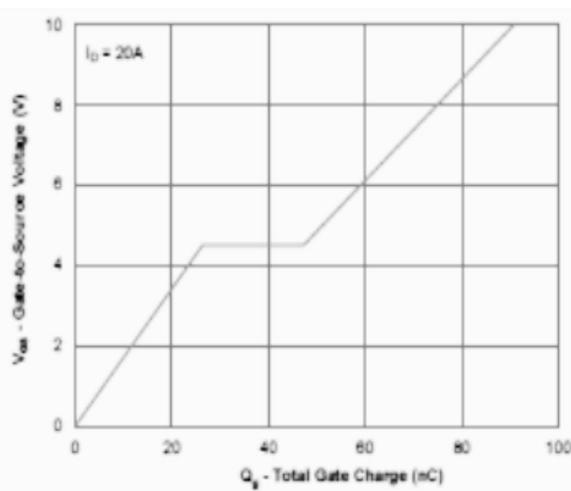


Fig.10 Capaoitance Characteristics

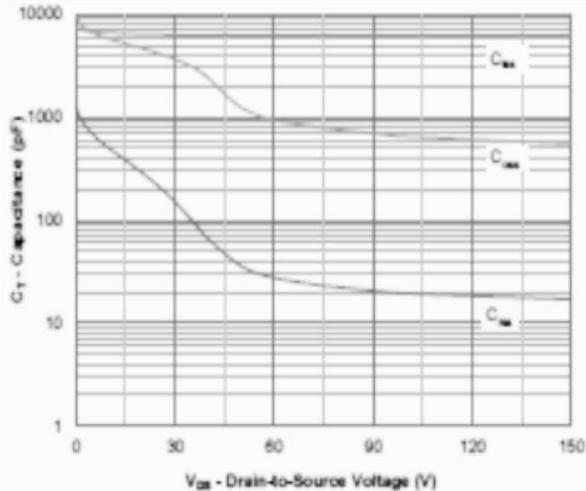


Fig.11 Power Dissipation

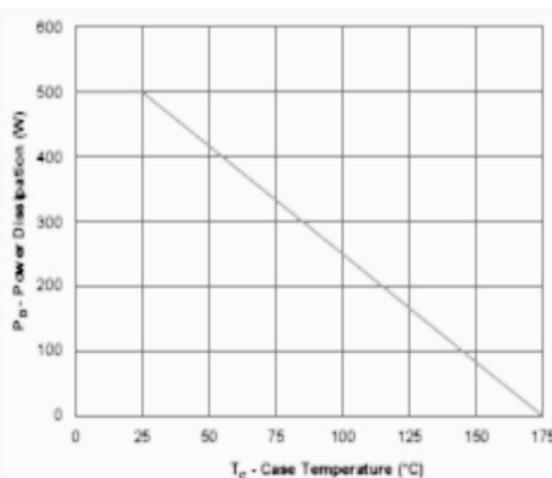
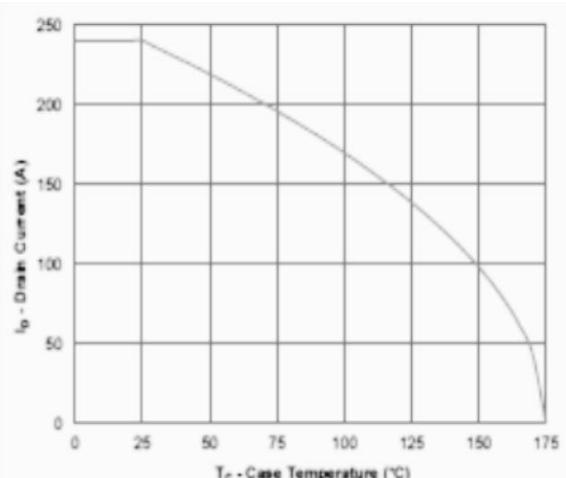
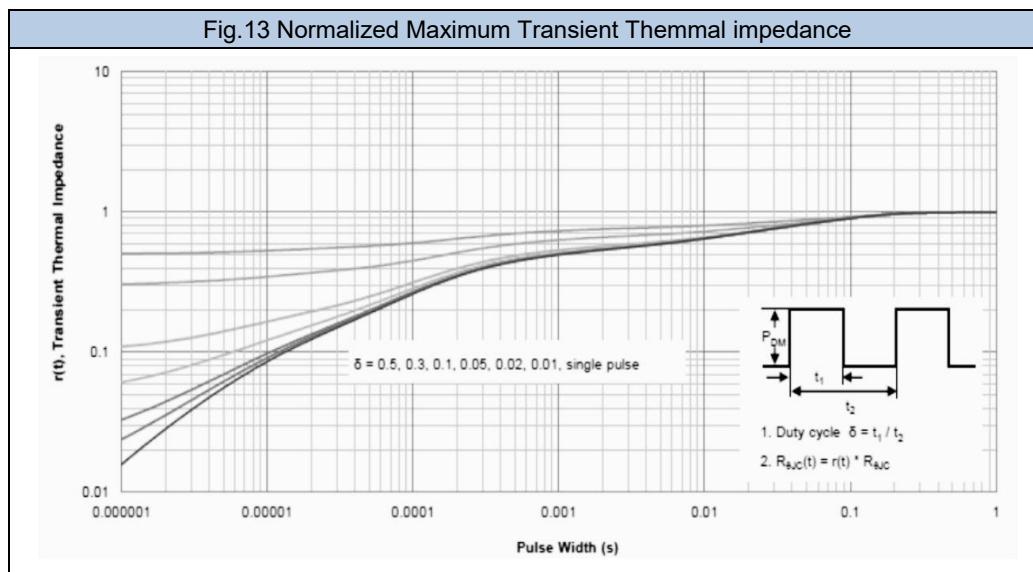


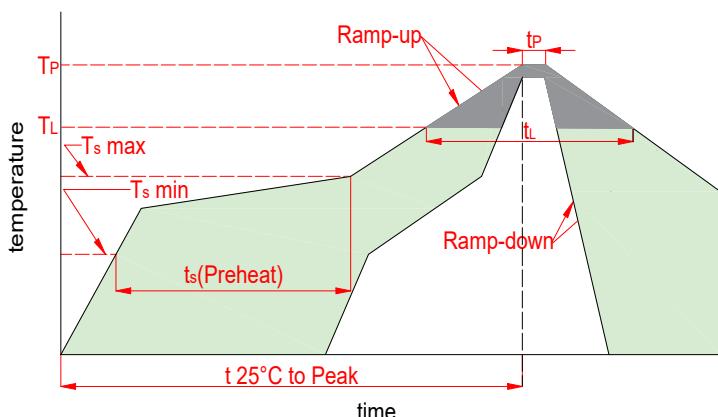
Fig.12 Drain Current Derating





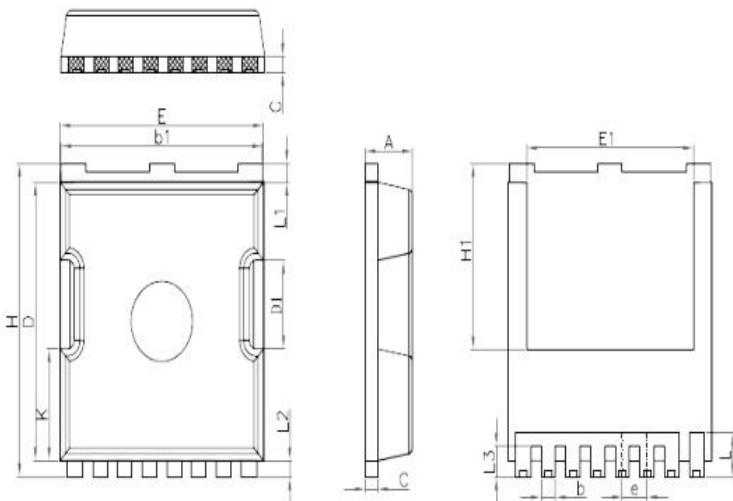


6. Soldering Parameters



Reflow Condition		Lead-free
Pre Heat	Temp. min(T_s (min))	150°C
	Temp. max(T_s (min))	200°C
	Time(min to max)(t_s)	60~180s
Aver. ramp up rate(Liquidus Temp.)(T_L)to peak	3°C/s max	
T_s (max) to T_L -Ramp-up Rate	3°C/s max	
Reflow	Temp.(T_L)(Liquidus)	217°C
	Temp.(t_p)(Liquidus)	60~150s
Peak Temp.(T_p)	260 ^{+0/-5} °C	
Time within actual peak Temp.(t_p)	30s max	
Ramp-down Rate	6°C/s max	
Time 25°C to peak Tempe.(T_p)	8 minutes max	
Do not exceed	260°C	

7. Dimensions



Dimensions	Inches		Millimeters	
	Min	Max	Min	Max
A	0.087	0.094	2.20	2.40
b	0.024	0.031	0.60	0.80
b1	0.380	0.390	9.65	9.90
C	0.016	0.024	0.40	0.60
D	0.405	0.411	10.28	10.45
D1	0.126	0.134	3.20	3.40
E	0.386	0.394	9.80	10.00
e	0.043	0.051	1.10	1.30
H	0.413	0.465	10.48	11.80
L1	0.024	0.031	0.60	0.80
L2	0.020	0.028	0.50	0.70

8. Package Information

Package	Quantity(pcs)
TOLL	2000



Important Notice and Disclaimer

- Reproducing and modifying information of the document is prohibited without from XINNUO.
- XINNUO reserves the right to make changes to this document and its products and specifications.
- XINNUO disclaims any and all liability arising out of the application or use of any product including damages incidentally and consequentially occurred.
- XINNUO does not assume any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.
- Applications shown on the here in document are examples of standard use and operation. Customers are responsible in comprehending the suitable use in particular applications.XINNUO makes no representation or warranty that such applications will be suitable for the specified use without further testing or modification.
- The products shown her are not designed and authorized for equipments requiring high level of reliability or relating to human life and for any applications concerning life-saving or life-sustaining, such as medical instruments, transportation equipment, aerospace machinery et cetera. Customers using or selling these products for use in such applications do so at their own risk and agree to fully indemnify XINNUO for any damages resulting from such improper use or sale.
- Since XINNUO uses lot number as the tracking base, please provide the lot number for tracking when complaining.